onsemi

MARKING

TinyLogic UHS 3-Input NOR Gate

NC7SZ27

Description

The NC7SZ27 is a single 3–Input NOR Gate from ON Semiconductor's Ultra High Speed Series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra high speed with high output drive while maintaining low static power dissipation over a very broad V_{CC} operating range. The device is specified to operate over the 1.65 V to 5.5 V V_{CC} range. The inputs and output are high impedance when V_{CC} operating voltage.

Features

- Space Saving SC-88 6-Lead Package
- Ultra Small MicroPakTM Leadless Package
- Ultra High Speed: t_{PD} = 2.9 ns Typ into 50 pF at 5 V V_{CC}
- High Output Drive: ±24 mA at 3 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V 5.5 V
- Power Down High Impedance Inputs / Output
- Overvoltage Tolerant Inputs Facilitate 5 V to 3 V Translation
- Patented Noise / EMI Reduction Circuitry Implemented
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

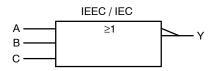
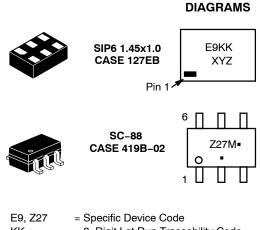


Figure 1. Logic Symbol



L9, ZZ1	- Opecilic Device Odde
KK	= 2-Digit Lot Run Traceability Code
XY	= 2-Digit Date Code Format
Z	= Assembly Plant Code
М	= Date Code*
-	= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet. NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 6.

Connection Diagrams

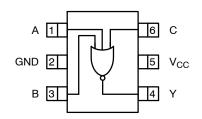
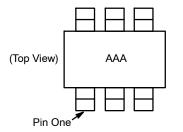


Figure 2. SC-88 (Top View)



AAA represents Product Code Top Mark - see ordering code.

NOTE: Orientation of Top Mark determines Pin One location. Read the Top Product Code Mark left to right, Pin One is the lower left pin (see diagram).

Figure 3. Pin 1 Orientation

PIN DESCRIPTIONS

Pin Name	Description
A, B, C	Inputs
Y	Output

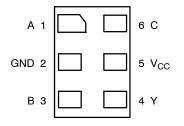


Figure 4. MicroPak (Top Through View)

FUNCTION	TABLE (Y =	$=\overline{A+B+C}$
----------	------------	---------------------

	Inputs					
Α	В	С	Y			
Н	Х	Х	L			
Х	Н	Х	L			
Х	Х	Н	L			
L	L	L	Н			

H = HIGH Logic Level L = LOW Logic Level

X = Don't Care

ABSOLUTE MAXIMUM RATINGS

Symbol	Paran	neter	Min	Мах	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
V _{IN}	DC Input Voltage		-0.5	6.5	V
V _{OUT}	DC Output Voltage		-0.5	6.5	V
Ι _{ΙΚ}	DC Input Diode Current	V _{IN} < 0 V	-	-50	mA
I _{OK}	DC Output Diode Current	V _{OUT} < 0 V	-	-50	mA
I _{OUT}	DC Output Current		-	±50	mA
I_{CC} / I_{GND}	DC V _{CC} / GND Current		-	±50	mA
T _{STG}	Storage Temperature		-65	+150	°C
TJ	Junction Temperature under Bia	S	-	+150	°C
ΤL	Junction Lead Temperature (Sol	dering, 10 Seconds)	-	+260	°C
PD	Power Dissipation in Still Air	SC-88	-	332	mW
		MicroPak	-	812	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage Operating		1.65	5.5	V
	Supply Voltage Data Retention		1.5	5.5	
V _{IN}	Input Voltage		0	5.5	V
V _{OUT}	Output Voltage		0	V _{CC}	V
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	Input Rise and Fall Time	V_{CC} @ 1.8 V, 2.5 V ±0.2 V	0	20	ns/V
		$V_{CC} @ 3.3 V \pm 0.3 V$	0	10	
		$V_{CC} @ 5.0 V \pm 0.5 V$	0	5	
θ_{JA}	Thermal Resistance	SC-88	-	377	°C/W
		MicroPak	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.



DC ELECTICAL CHARACTERISTICS

					T,	λ = +25°	°C	T _A = -40	to +85°C										
Symbol	Parameter	V _{CC} (V)	Co	nditions	Min	Тур	Max	Min	Max	Unit									
VIH	HIGH Level Input	1.65 to 1.95			0.65 V _{CC}	-	-	0.65 V _{CC}	-	V									
	Voltage	2.3 to 5.5			0.70 V _{CC}	-	-	0.70 V _{CC}	_										
VIL	LOW Level Input	1.65 to 1.95			-	-	0.35 V _{CC}	_	0.35 V _{CC}	V									
	Voltage	2.3 to 5.5			-	-	0.30 V _{CC}	_	0.30 V _{CC}										
V _{OH}	HIGH Level Output	1.65	$V_{IN} = V_{IH}$	I_{OH} = -100 μ A	1.55	1.65	-	1.55	-	V									
	Voltage	2.3	or V _{IL}		2.2	2.3	-	2.2	-										
		3.0	.0		2.9	3.0	-	2.9	-										
		4.5			4.4	4.5	-	4.4	-										
		1.65		I _{OH} = -4 mA	1.29	1.52	-	1.29	-										
		2.3		I _{OH} = -8 mA	1.9	2.15	-	1.9	-										
		3.0				I _{OH} = -16 mA	2.4	2.80	-	2.4	-								
		3.0		I _{OH} = -24 mA	2.3	2.68	-	2.3	-										
		4.5		I _{OH} = -32 mA	3.8	4.20	-	3.8	-										
V _{OL}	LOW Level Output	1.65	or V _{IL}	I _{OL} = 100 μA	-	0.0	0.1	_	0.1	V									
	Voltage	2.3		or V _{IL}	or v _{IL}	or v _{IL}	or v _{IL}		-	0.0	0.1	_	0.1						
		3.0				-	0.0	0.1	_	0.1									
		4.5													-	0.0	0.1	_	0.1
		1.65		I _{OL} = 4 mA	-	0.08	0.24	-	0.24										
		2.3		I _{OL} = 8 mA	-	0.10	0.3	-	0.3										
		3.0		I _{OL} = 16 mA	-	0.15	0.4	-	0.4										
		3.0		I _{OL} = 24 mA	-	0.22	0.55	-	0.55										
		4.5		I _{OL} = 32 mA	-	0.22	0.55	-	0.55										
I _{IN}	Input Leakage Current	1.65 to 5.5	V _{IN} = 5.5 \	/, GND	_	-	±1	-	±10	μΑ									
I _{OFF}	Power Off Leakage Current	0.0	V _{IN} or V _{OL}	_{JT} = 5.5 V	_	-	1	_	10	μΑ									
ICC	Quiescent Supply Current	1.65 to 5.5	V _{IN} = 5.5 \	/, GND	-	-	2.0	-	20	μA									

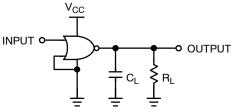


AC ELECTRICAL CHARACTERISTICS

					Γ _A = +25°C	;	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	t _{PHL} Propagation Delay (Figure 5, 7)	1.8 ±0.15	$C_{L} = 15 pF$,	-	10.0	18.5	-	19.0	ns
		2.5 ±0.2	$R_L = 1 M\Omega$	-	5.0	10.5	-	11.0	
		3.3 ±0.3		-	3.2	8.0	-	8.5	
		5.0 ±0.5		-	2.6	5.5	-	6.0	
		3.3 ±0.3	$C_{L} = 50 \text{ pF},$	-	3.9	8.0	-	8.5	
		5.0 ±0.5	R _L = 500 Ω	-	2.9	5.5	-	6.0	
C _{IN}	Input Capacitance	0		-	4	-	-	-	pF
C _{PD}	Power Dissipation Capacitance	3.3	(Note 2)	-	23	-	-	-	pF
	(Figure 6)	5.0	1	-	30	-	-	-	

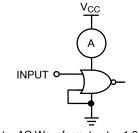
2. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. (See Figure 6) C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).

AC Loading and Waveforms

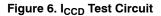


 C_L includes load and stray capacitance Input PRR = 1.0 MHz, t_W = 500 ns.

Figure 5. AC Test Circuit



 $\begin{array}{l} \mbox{Input} = AC \ Waveform; \ t_r = t_f = 1.8 \ ns; \\ \mbox{PRR} = 10 \ MHz; \ Duty \ Cycle = 50\%. \end{array}$



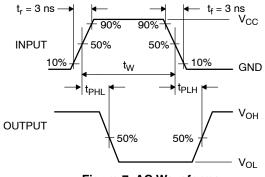


Figure 7. AC Waveforms



DEVICE ORDERING INFORMATION

Device	Top Mark	Packages	Shipping [†]
NC7SZ27P6X	Z27	6-Lead SC70, EIAJ SC88, 1.25 mm Wide	3000 / Tape & Reel

DISCONTINUED (Note 3)

NC7SZ27L6X	E9	6-Lead MicroPak, 1.00 mm Wide	5000 / Tape & Reel
NC7SZ27P6X-L22347	Z27	6-Lead SC70, EIAJ SC88, 1.25 mm Wide	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

3. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on <u>www.onsemi.com</u>.

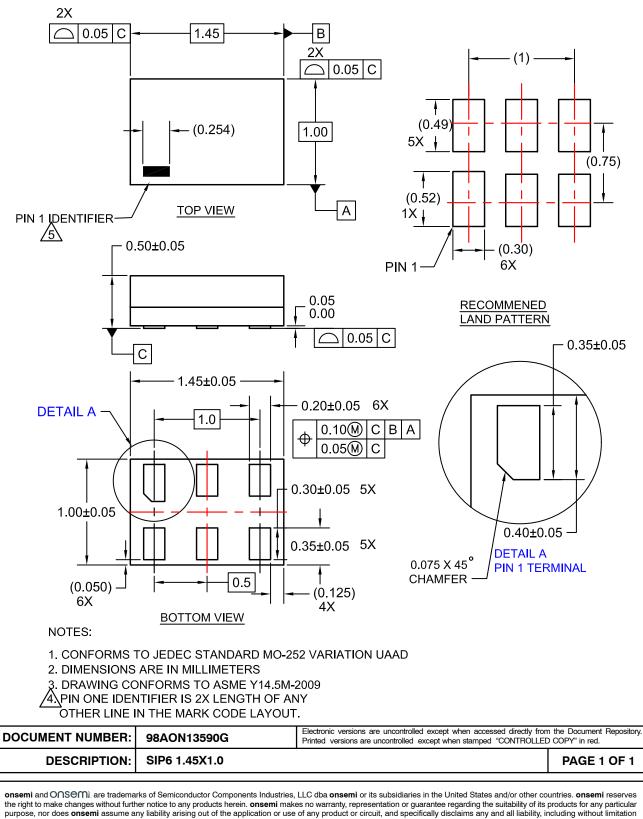
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SIP6 1.45X1.0 CASE 127EB ISSUE O

DATE 31 AUG 2016

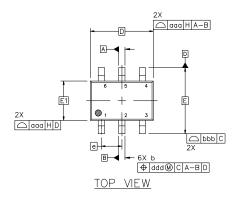


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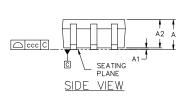
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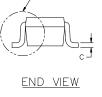
DATE 18 APR 2024



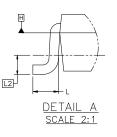


- DIMENSIONING AND TOLERANCING CONFORM TO ASME 1. Y14.5-2018.
- 2.
- ALL DIMENSION ARE IN MILLIMETERS. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 3. PER END.
- 4. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF
- DATUMS A AND B ARE DETERMINED AT DATUM H. 5.
- DIMENSIONS & AND C APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP. 6.
- DIMENSION & DOES NOT INCLUDE DAMBAR PROTRUSION. 7 ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION & AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.





DETAIL A



	MILLIMETERS					
DIM	MIN.	NOM.	MAX.			
A			1.10			
A1	0.00		0.10			
A2	0.70	0.90	1.00			
b	0.15	0.20	0.25			
С	0.08	0.15	0.22			
D	2.00 BSC					
E	2.10 BSC					
E1		1.25 BSC	;			
е		0.65 BSC)			
L	0.26	0.36	0.46			
L2		0.15 BSC				
aaa	0.15					
bbb	0.30					
ссс		0.10				
ddd		0.10				

6X 0.66 6X 0.30-2.50 0.65 PITCH

RECOMMENDED MOUNTING FOOTPRINT*

FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ONSEMI SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

XXX = Specific Device Code = Date Code* Μ

GENERIC **MARKING DIAGRAM***

XXXM-

. 0

6

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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DATE 18 APR 2024

STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2
STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2	STYLE 8: CANCELLED	STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2	STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2	STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2	STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2
STYLE 13:	STYLE 14:	STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:
PIN 1. ANODE	PIN 1. VREF	PIN 1. ANODE 1	PIN 1. BASE 1	PIN 1. BASE 1	PIN 1. VIN1
2. N/C	2. GND	2. ANODE 2	2. EMITTER 2	2. EMITTER 1	2. VCC
3. COLLECTOR	3. GND	3. ANODE 3	3. COLLECTOR 2	3. COLLECTOR 2	3. VOUT2
4. EMITTER	4. IOUT	4. CATHODE 3	4. BASE 2	4. BASE 2	4. VIN2
5. BASE	5. VEN	5. CATHODE 2	5. EMITTER 1	5. EMITTER 2	5. GND
6. CATHODE	6. VCC	6. CATHODE 1	6. COLLECTOR 1	6. COLLECTOR 1	6. VOUT1
STYLE 19:	STYLE 20:	STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:
PIN 1. I OUT	PIN 1. COLLECTOR	PIN 1. ANODE 1	PIN 1. D1 (i)	PIN 1. Vn	PIN 1. CATHODE
2. GND	2. COLLECTOR	2. N/C	2. GND	2. CH1	2. ANODE
3. GND	3. BASE	3. ANODE 2	3. D2 (i)	3. Vp	3. CATHODE
4. V CC	4. EMITTER	4. CATHODE 2	4. D2 (c)	4. N/C	4. CATHODE
5. V EN	5. COLLECTOR	5. N/C	5. VBUS	5. CH2	5. CATHODE
6. V REF	6. COLLECTOR	6. CATHODE 1	6. D1 (c)	6. N/C	6. CATHODE
STYLE 25:	STYLE 26:	STYLE 27:	STYLE 28:	STYLE 29:	STYLE 30:
PIN 1. BASE 1	PIN 1. SOURCE 1	PIN 1. BASE 2	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. SOURCE 1
2. CATHODE	2. GATE 1	2. BASE 1	2. DRAIN	2. ANODE	2. DRAIN 2
3. COLLECTOR 2	3. DRAIN 2	3. COLLECTOR 1	3. GATE	3. COLLECTOR	3. DRAIN 2
4. BASE 2	4. SOURCE 2	4. EMITTER 1	4. SOURCE	4. EMITTER	4. SOURCE 2
5. EMITTER	5. GATE 2	5. EMITTER 2	5. DRAIN	5. BASE/ANODE	5. GATE 1
6. COLLECTOR 1	6. DRAIN 1	6. COLLECTOR 2	6. DRAIN	6. CATHODE	6. DRAIN 1

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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